

## NPN Low Vce(sat) Transistor

Voltage

100V

Current

1A

### **Features**

- Silicon NPN epitaxial type
- Low Vce(sat) 0.35V(max)@Ic/lb= 500mA / 50mA
- High collector current capability
- Excellent DC current gain characteristics
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC61249 Standard
- PNP complement: PBHV9110DW-AU

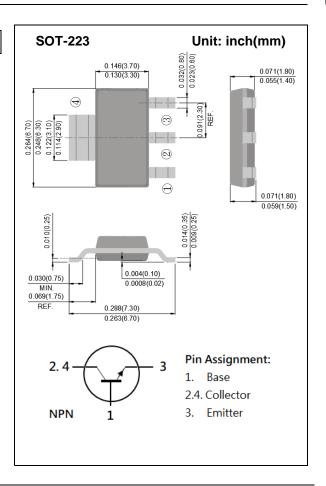
### **Mechanical Data**

• Case: SOT-223 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.123 grams

Marking: 8110DW



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Collector-Base Voltage	V <sub>CBO</sub>	120	V
Collector-Emitter Voltage	Vceo	100	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Collector Current (DC)	Ic	1	Α
Collector Current (Pulse)	I <sub>CP</sub>	3	Α
Power Dissipation	P <sub>D</sub>	2.6	W
Junction Temperature	TJ	150	°C
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Thermal Resistance from Junction to Ambient (Note)	$R_{ heta JA}$	48	°C/W

Note: Mounted on FR4 PCB at 1 inch square copper pad.



## **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
OFF Characteristics							
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub> I <sub>C</sub> = 10mA, I <sub>B</sub> = 0A		100	-	-	V	
Collector-Base Breakdown Voltage	ВУсво	I <sub>C</sub> = 0.1mA, I <sub>E</sub> = 0A	120	-	-	V	
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	I <sub>E</sub> = 0.1mA, I <sub>C</sub> = 0A	6	-	-	V	
Collector Cutoff Current	Ісво	V <sub>CB</sub> = 120V, I <sub>E</sub> = 0A	-	-	500	nA	
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> = 6V, I <sub>C</sub> = 0A	-	-	500	nA	
ON characteristics							
DC Current Gain (Note1)	hfE	V <sub>CE</sub> = 2V, I <sub>C</sub> = 150mA	140	-	330	-	
		V <sub>CE</sub> = 5V, I <sub>C</sub> = 500mA	100	-	300		
		V <sub>CE</sub> = 5V, I <sub>C</sub> = 1A	40	-	-		
Collector-Emitter Saturation Voltage (Note1)	VCE(SAT)	Ic= 0.1A, I <sub>B</sub> = 10mA	-	38	120	mV	
		Ic= 0.5A, I <sub>B</sub> = 50mA	-	117	350		
		I <sub>C</sub> = 1A, I <sub>B</sub> = 0.1A	-	220	450		
Base-Emitter Saturation voltage	.,	Ic= 0.1A, I <sub>B</sub> = 10mA	-	-	1.0	.,,	
(Note1)	V <sub>BE(SAT)</sub>	I <sub>C</sub> = 0.5A, I <sub>B</sub> = 50mA	-	-	1.1	V	
Transition Frequency	f⊤	V <sub>CE</sub> = 5V, I <sub>E</sub> = -50mA	100	-	-	MHz	
Collector Output Capacitance	0	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0A,			10	, F	
	Сов	f=1MHz	-	-	10	pF	

Note: 1. Pulse width<a></a>300us, Duty cycle<a></a>2%



#### **TYPICAL CHARACTERISTIC CURVES**

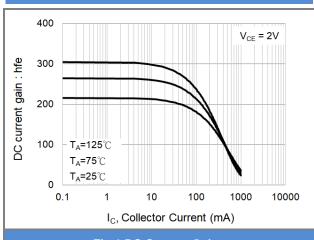


Fig.1 DC Current Gain

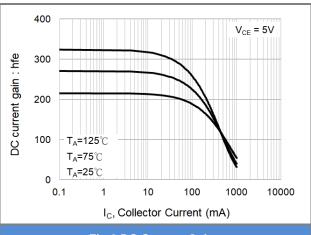


Fig.2 DC Current Gain

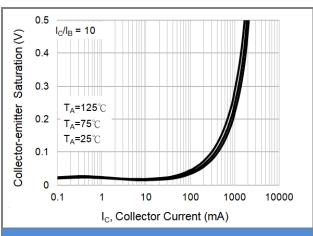
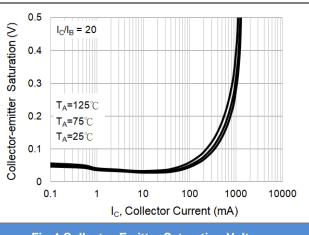
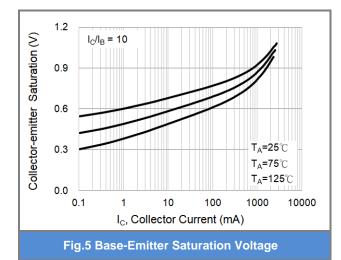
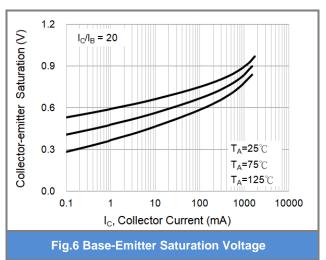


Fig.3 Collector-Emitter Saturation Voltage



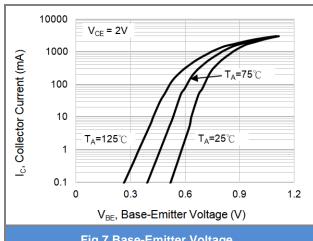
**Fig.4 Collector-Emitter Saturation Voltage** 



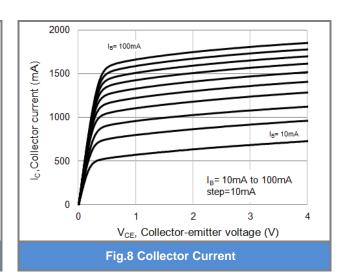




#### **TYPICAL CHARACTERISTIC CURVES**







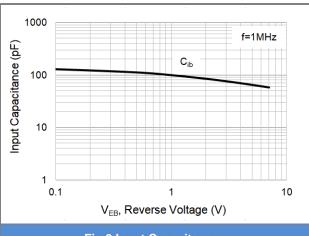
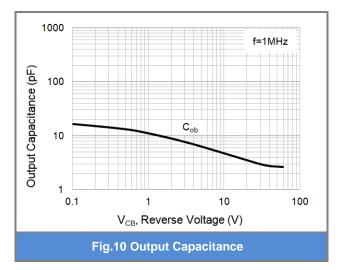
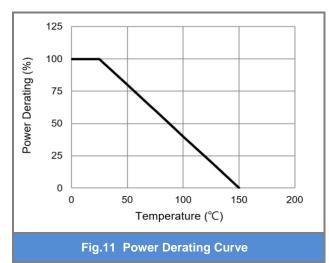


Fig.9 Input Capacitance



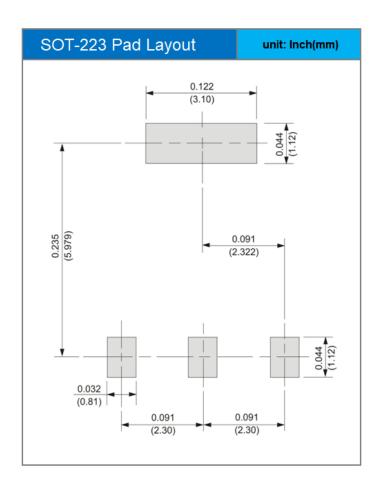




## **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
PBHV8110DW-AU	SOT-223	2,500 pcs / 13" reel	8110DW	

## **Mounting Pad Layout**





### Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are
  responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no
  representation or warranty that such applications will be suitable for the specified use without further testing or
  modification.
- The products shown herein are not designed and authorized for equipments relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.